NSN 5961-01-625-3406

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-625-3406 **Inclosure Material:** Ceramic **Overall Length:** 92.0 millimeters **Overall Height:** 30.0 millimeters **Overall Width:** 20.8 millimeters **Mounting Facility Quantity: Mounting Method:** Threaded stud Voltage Rating In Volts Per Characteristic: 1.38 forward voltage, peak and 1600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 36.0 amperes forward current, repetitive, peak total value and 10.0 milliamperes reverse current, peak **Power Rating Per Characteristic:** 125.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** -40.0 degrees celsius ambient air and 125.0 degrees celsius ambient air **Product Name:** Dual diode module **Special Features:** Dual **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No